

No.2555A

2 S B 1 3 0 2

PNP Epitaxial Planar Silicon Transistor

High-Current Switching Applications

Applications

. DC-DC converters, motor drivers, relay drivers, lamp drivers

Features

- . Adoption of FBET, MBIT processes
- . Low collector to emitter saturation voltage
- . Large current capacity
- . Fast switching speed
- . Very small size making it easy to provide high-density, small-sized hybrid

Absolute Maximum Ratings at Ta=	25 ⁰ C				unit
Collector to Base Voltage	VCBO			-25	V
Collector to Emitter Voltage	VCEO			-20	V
Emitter to Base Voltage	VEBO			- 5	V
Collector Current	IC			- 5	A
Collector Current(Pulse)	I_{CP}			-8	A
Collector Dissipation	PC	on ceramic x 0.8mm)	board	1.3	W
Junction Temperature	Тj	•		150	°C
Storage Temperature	Tstg		-55 to		°Č

Electrical Characteristics Collector Cutoff Current Emitter Cutoff Current DC Current Gain	at Ta=25' ICBO IEBO hFE(1) hFE(2)	V _{CB} =-20V, I _E =0 V _{EB} =-4V, I _C =0 V _{CE} =-2V, I _C =-500mA V _{CE} =-2V, I _C =-4A	min typ 100* 60	-500 -500 400	unit nA nA
Output Capacitance	f _T cob VCE(sat)	V _{CE} =-5V,I _C =-200mA V _{CB} =-10V,f=1MHz		-500 -1.3	MHz pF mV V

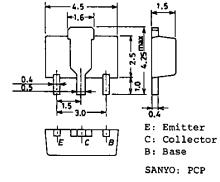
*: The 2SB1302 is classified by 500mA hre as follows:

100 R 200 140 S 280 200 T 400				
	100 R 200	140 S 280	200 T	400

Marking : BJ hFE rank: R,S,T

Package Dimensions 2038

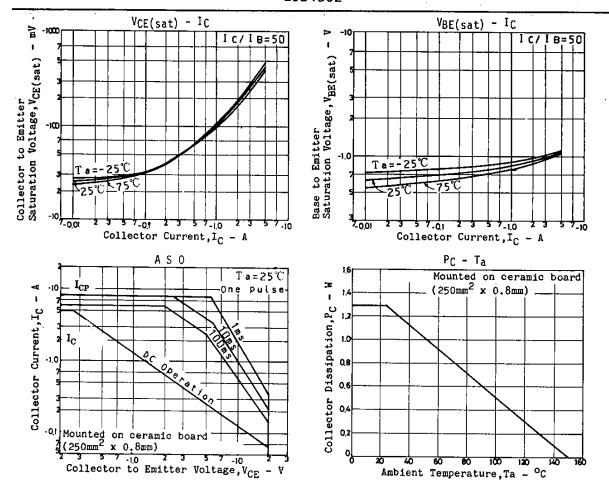
(unit:mm)



(Bottom View)

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Continued from preceding page.		min		
C-B Breakdown Voltage C-E Breakdown Voltage E-B Breakdown Voltage Turn-on Time Storage Time Fall Time V(BR) V(BR) ton tstg	CBO I_C =-10 μ A, I_E =0 CEO I_C =-1 m A, R_{BE} =0 EBO I_E =-10 μ A, I_C =0 See specified	min -25 -20 -5 Test Circuit.	40 200 10	unit V V V ns ns
Switching Time Test Circuit PW=	20µs ∐ IBI 19. RB			
	1NPUT VR # 1B2 ₹50	RL ₹	e : Ω, Capacitanc	e : F)
-100mA		40mA -35mA		
90mA - 40mA		-30m/	4	
	Collector Current, IC	-2	5mA	
Ollector Current, 10 - 30 m W	- ent		-20mA	
- 20mA			-15mA	
L -2	5 ·2		-10mA	
3 -10mA	i i			
i i			-5mA	
- 	- 		 	
0 -02 -0.4 -0.6 -0.8	-1.0 O	-1 -2 -3	I B=0	,
Collector to Emitter Voltage, V _C IC - VBE	E - V Coll	ector to Emitter Vol	tage, V _{CE} - V	
	= - 2 V		V c E = - 2V	
1 -5				
	Gain, hFE	T. 35°C		
Collector Current, I _C	ni a	T a = 75 °C		
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5 ,	DC Current	-25℃		
3 -2	ä ,			
i	2 4		+ + + + + + + + + + + + + + + + + + + +	
8 -	3			
0 -02 -04 -05 -08 -10	2 1.2 -1,4 27-0,01	2 3 5 7-Q ₁ 2 3 5 7	1.0 2 3 5 7 ₋₁	ļ
Base to Emitter Voltage, VRE	- V	Collector Current,	I _C - A	•
F 1000 FT - IC VCE	=-50	Cob - VCB	f - 11111-	1
¥ 7-1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	┈┤╌┤ ┈┤		f = 1MHz	
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Cain-Bandwidth Product, fr	Output: Capacitance, cob			
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7-00 2 3 3 7-0 2 3 5 7-10 2 3 Collector Current, I C - A	5 7 ₁₀ 3 Ĉo	3 7 10 2 3 5 llector to Base Volta	7 -10 2 2 3 age VCP - V	3
			C-1.CB	



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